

**MOTOROLA
SEMICONDUCTOR
TECHNICAL DATA**

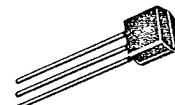
NPN Silicon High Frequency Transistors

... designed for low noise, wide dynamic range front-end amplifiers and low-noise VCO's. Available in two surface-mountable plastic package styles, as well as the popular TO-92 package. This Motorola series of small-signal plastic transistors offers superior quality and performance at low cost.

- High Gain-Bandwidth Product
 $f_T = 7 \text{ GHz (Typ)} @ 30 \text{ mA}$
- Low Noise Figure
 $\text{NF} = 1.7 \text{ dB (Typ)} @ 500 \text{ MHz}$
- High Gain
 $G_{NF} = 17 \text{ dB (Typ)} @ 10 \text{ mA}/500 \text{ MHz}$
- State-of-the-Art Technology
 - Fine Line Geometry
 - Ion-Implanted Arsenic Emitters
 - Gold Top Metallization and Wires
 - Silicon Nitride Passivation
- Tape and Reel Packaging Options
- MMBR911 Available in Low Profile, Add L Suffix

**MPS911
MXR911
MMBR911**

**LOW NOISE
HIGH RF GAIN**



TO-92
CASE 29
MPS911



SOT-89
CASE 345
MXR911



SOT-23
CASE 318
MMBR911
Standard and Low Profile

MAXIMUM RATINGS

Ratings	Symbol	MPS911	MXR911	MMBR911	Unit
Collector-Emitter Voltage	V_{CEO}	12			Vdc
Collector-Base Voltage	V_{CBO}	20			Vdc
Emitter-Base Voltage	V_{EBO}	3			Vdc
Collector Current — Continuous	I_C	60			mA
Power Dissipation @ $T_A = 25^\circ\text{C}$	P_D	625	400 (Free Air)	200 (Free Air)	mW
Storage Temperature	T_{stg}	-55 to +150			°C



MOTOROLA

DS4642

MOTOROLA SC (XSTRS/R F)

71 DE 6367254 0073003 4

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage ($I_C = 1 \text{ mA}_\text{dc}$, $I_B = 0$)	$V_{(\text{BR})\text{CEO}}$	12	—	—	Vdc
Collector-Base Breakdown Voltage ($I_C = 0.1 \text{ mA}_\text{dc}$, $I_E = 0$)	$V_{(\text{BR})\text{CBO}}$	20	—	—	Vdc
Emitter-Base Breakdown Voltage ($I_E = 0.1 \text{ mA}$, $I_C = 0$)	$V_{(\text{BR})\text{EBO}}$	3	—	—	Vdc
Collector Cutoff Current ($V_{\text{CB}} = 15 \text{ Vdc}$, $I_E = 0$)	I_{CBO}	—	—	50	nA _{dc}
ON CHARACTERISTICS					
DC Current Gain ($I_C = 30 \text{ mA}_\text{dc}$, $V_{\text{CE}} = 10 \text{ Vdc}$)	h_{FE}	30	—	200	—

DYNAMIC CHARACTERISTICS

Collector-Base Capacitance ($V_{\text{CB}} = 10 \text{ Vdc}$, $I_E = 0$, $f = 1 \text{ MHz}$)	C_{cb}	—	—	1	pF
Current Gain-Bandwidth Product ($V_{\text{CE}} = 10 \text{ Vdc}$, $I_C = 30 \text{ mA}_\text{dc}$, $f = 1 \text{ GHz}$)	f_T	—	7	—	GHz
MPS911	—	7	—	—	
MXR911	—	7	—	—	
MMBR911	—	6	—	—	

FUNCTIONAL TESTS

Gain @ Noise Figure ($I_C = 10 \text{ mA}_\text{dc}$, $V_{\text{CE}} = 10 \text{ Vdc}$)	MPS911	$f = 0.5 \text{ GHz}$	G _{NF}	—	16.5	—	dB
		$f = 1 \text{ GHz}$	—	11	—	—	
	MXR911	$f = 0.5 \text{ GHz}$	—	16	—	—	
		$f = 1 \text{ GHz}$	—	8.5	—	—	
	MMBR911	$f = 0.5 \text{ GHz}$	—	17	—	—	
		$f = 1 \text{ GHz}$	—	11	—	—	
Noise Figure ($I_C = 10 \text{ mA}_\text{dc}$, $V_{\text{CE}} = 10 \text{ Vdc}$)	MPS911	$f = 0.5 \text{ GHz}$	NF	—	1.7	—	dB
		$f = 1 \text{ GHz}$	—	2.7	—	—	
	MXR911	$f = 0.5 \text{ GHz}$	—	2	—	—	
		$f = 1 \text{ GHz}$	—	2.6	—	—	
	MMBR911	$f = 0.5 \text{ GHz}$	—	2	—	—	
		$f = 1 \text{ GHz}$	—	2.9	—	—	

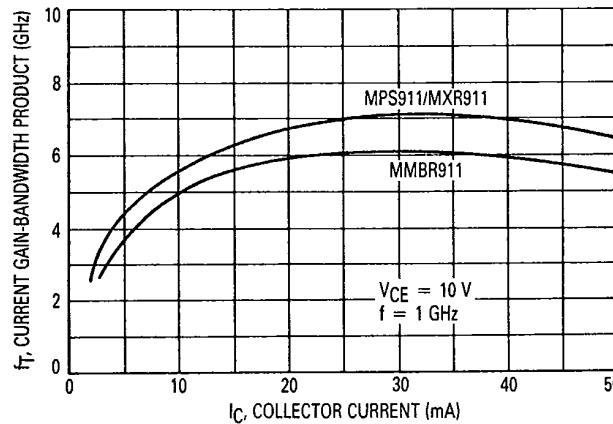
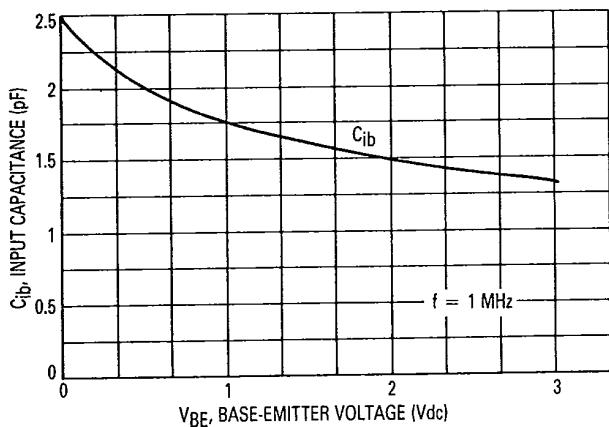
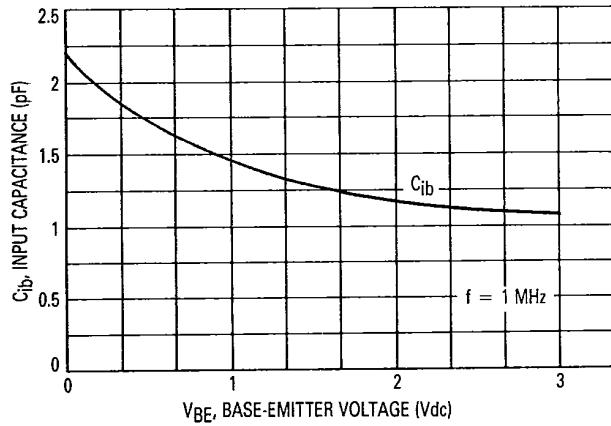


Figure 1. Current Gain-Bandwidth versus Collector Current @ 1 GHz

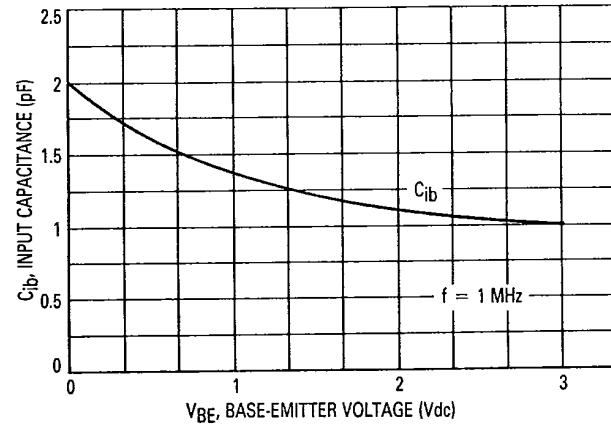
MOTOROLA SC CXSTRS/R F

Figure 2. Input Capacitance versus
Base-Emitter Voltage

(a) TO-92 MPS911

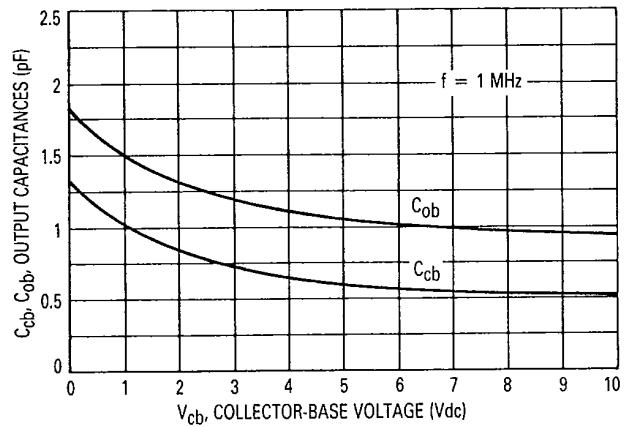


(b) SOT-89 MXR911

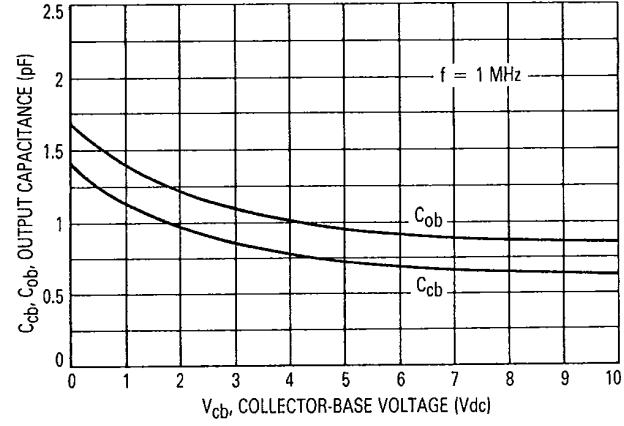


(c) SOT-23 MMBR911

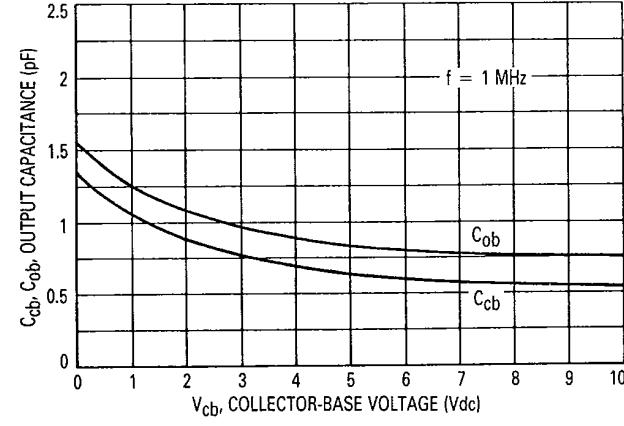
71 DE 6367254 0073004 6

Figure 3. Output Capacitances versus
Collector-Base Voltage

(a) TO-92 MPS911



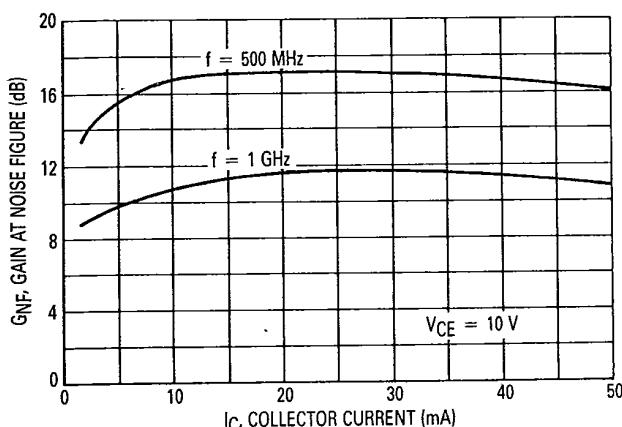
(b) SOT-89 MXR911



(c) SOT-23 MMBR911

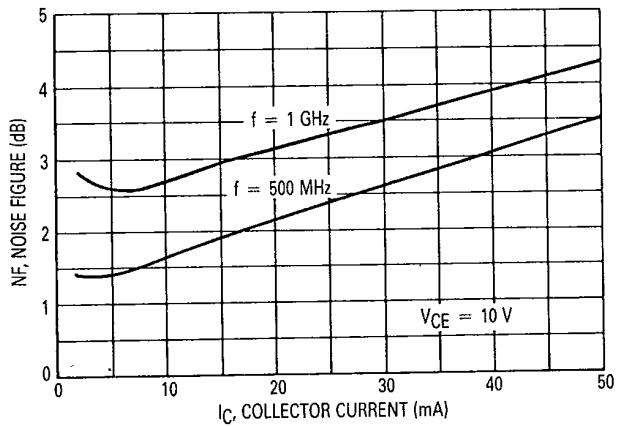
MOTOROLA SC (XSTRS/R F)

Figure 4. Gain at Noise Figure versus Collector Current

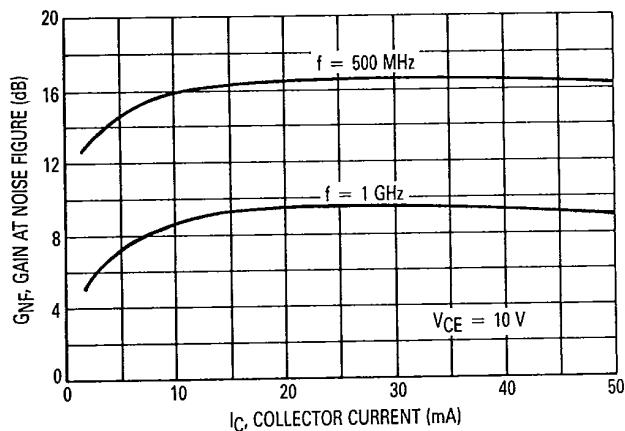


(a) TO-92 MPS911

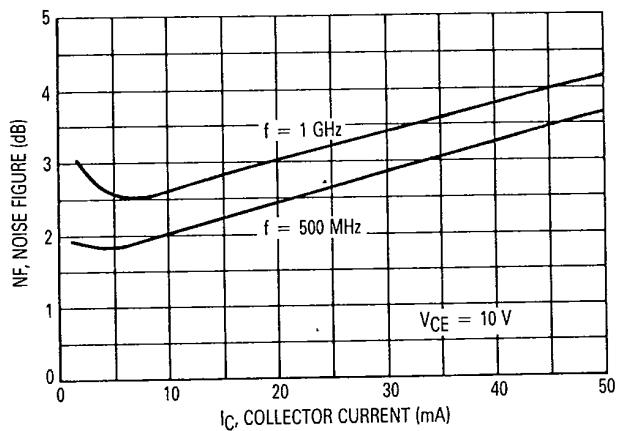
Figure 5. Noise Figure versus Collector Current



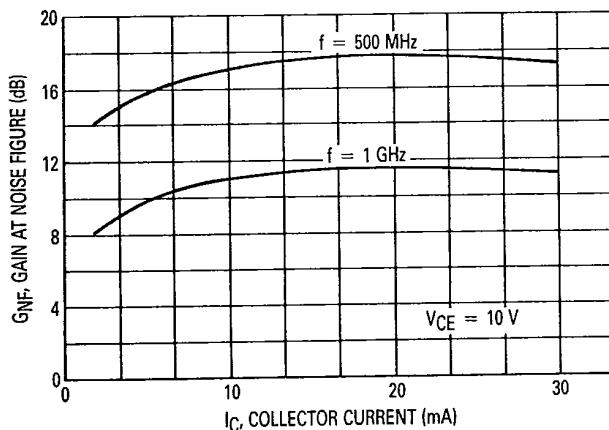
(a) TO-92 MPS911



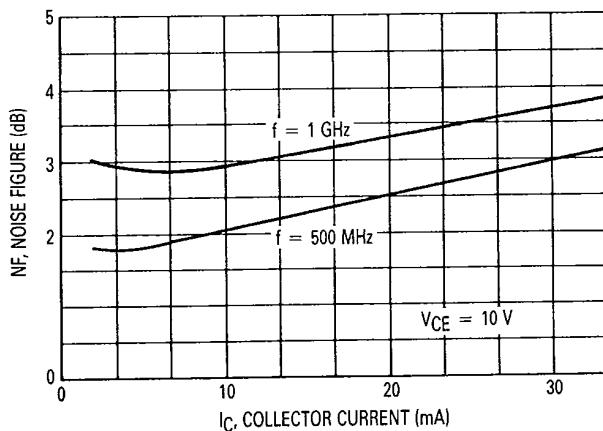
(b) SOT-89 MXR911



(b) SOT-89 MXR911



(c) SOT-23 MMBR911

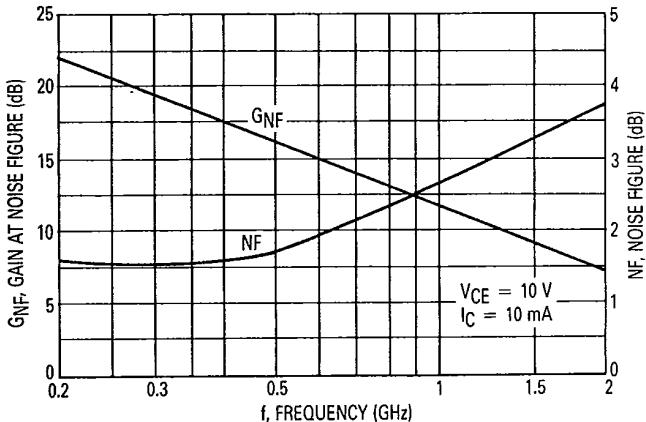


(c) SOT-23 MMBR911

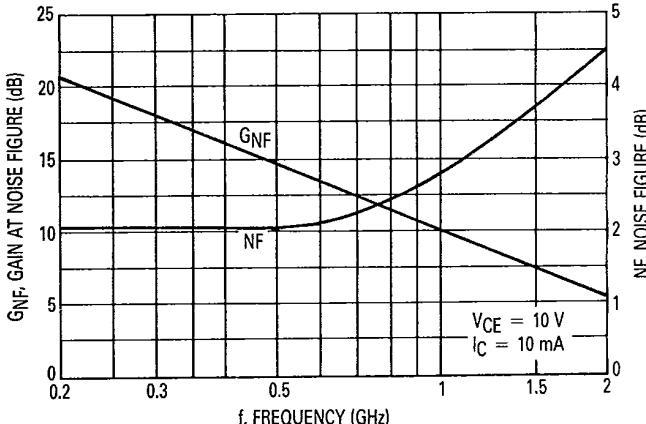
MOTOROLA SC {XSTRS/R F}

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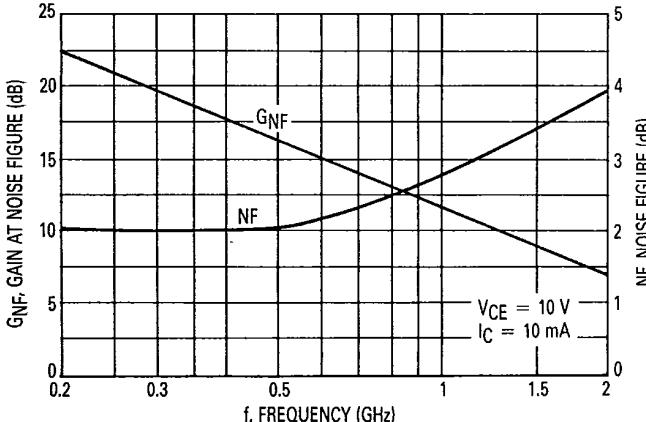
Figure 6. Gain at Noise Figure and Noise Figure versus Frequency



(a) TO-92 MPS911

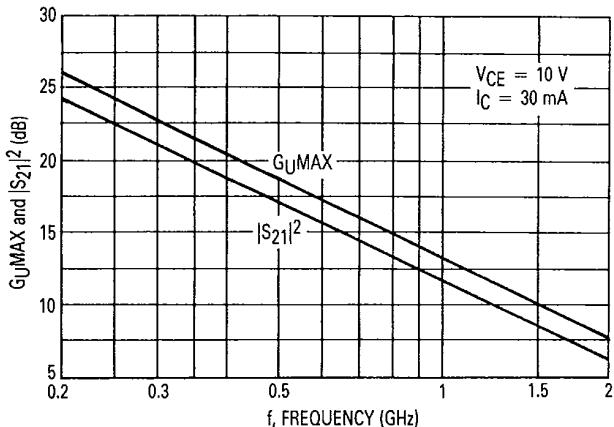


(b) SOT-89 MXR911

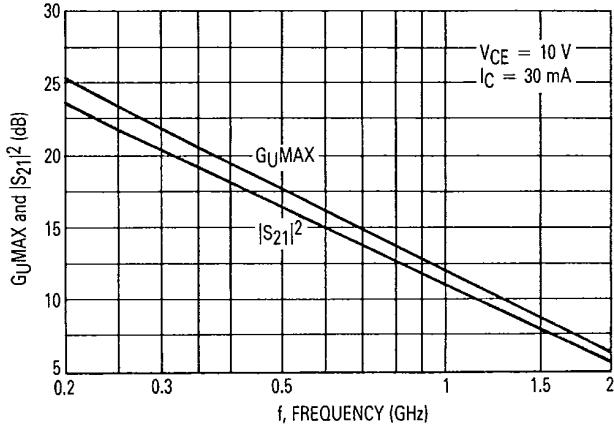


(c) SOT-23 MMBR911

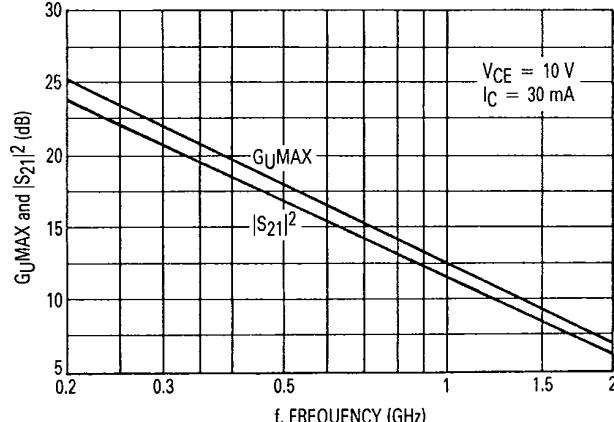
Figure 7. Maximum Unilateral Gain and Insertion Gain versus Frequency



(a) TO-92 MPS911

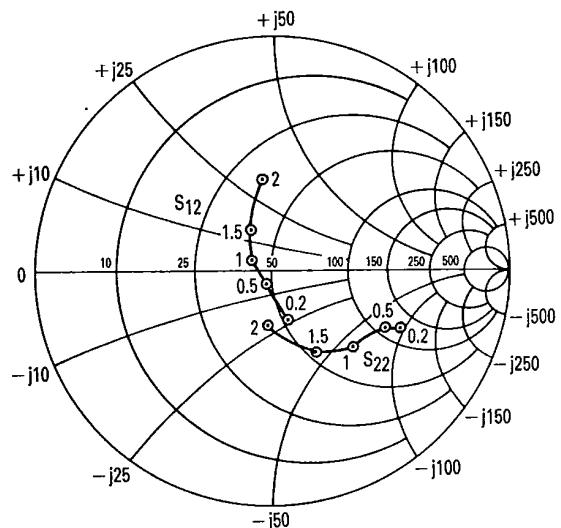


(b) SOT-89 MXR911

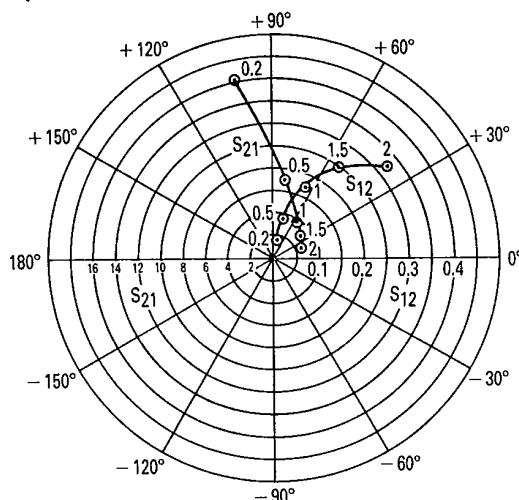


(c) SOT-23 MMBR911

TO-92 MPS911



INPUT AND OUTPUT REFLECTION COEFFICIENTS
versus FREQUENCY
 $V_{CE} = 10$ V, $I_C = 30$ mA



FORWARD AND REVERSE TRANSMISSION
COEFFICIENTS versus FREQUENCY
 $V_{CE} = 10$ V, $I_C = 30$ mA

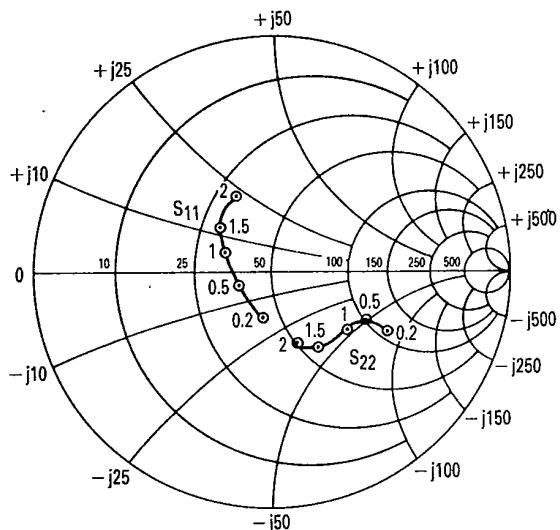
COMMON Emitter S-PARAMETERS

V_{CE} (Volts)	I_C (mA)	f (MHz)	S_{11}		S_{21}		S_{12}		S_{22}	
			$ S_{11} $	$\angle \phi$	$ S_{21} $	$\angle \phi$	$ S_{12} $	$\angle \phi$	$ S_{22} $	$\angle \phi$
10	2	200	0.78	-46	4.42	134	0.06	69	0.95	-18
		500	0.46	-107	3.35	98	0.10	56	0.78	-30
		1000	0.30	172	2.23	61	0.14	54	0.66	-48
		1500	0.41	118	1.66	34	0.20	51	0.57	-70
		2000	0.60	89	1.43	11	0.29	45	0.46	-107
	5	200	0.72	-55	8.75	126	0.05	68	0.87	-23
	500	0.31	-107	5.23	92	0.09	63	0.68	-31	
	1000	0.18	178	3.05	61	0.15	60	0.57	-46	
	1500	0.27	122	2.22	38	0.22	52	0.50	-66	
	2000	0.45	94	1.90	17	0.30	43	0.38	-97	
	10	200	0.48	-64	12.79	114	0.04	73	0.74	-24
	500	0.16	-100	6.19	85	0.09	71	0.60	-29	
	1000	0.09	165	3.45	59	0.17	63	0.50	-44	
	1500	0.22	112	2.50	36	0.25	50	0.41	-65	
	2000	0.41	90	2.14	16	0.32	38	0.26	-98	
	20	200	0.29	-67	15.30	106	0.04	78	0.65	-23
	500	0.08	-92	6.76	82	0.09	75	0.55	-27	
	1000	0.06	144	3.71	58	0.17	64	0.46	-43	
	1500	0.20	108	2.65	30	0.25	51	0.37	-63	
	2000	0.38	89	2.25	18	0.32	38	0.23	-94	
	30	200	0.20	-70	16.04	103	0.04	80	0.61	-22
	500	0.05	-97	6.90	81	0.09	77	0.53	-25	
	1000	0.07	138	3.76	58	0.17	66	0.46	-41	
	1500	0.20	109	2.68	38	0.25	52	0.37	-61	
	2000	0.38	90	2.28	20	0.32	40	0.24	-91	
	50	200	0.13	-78	15.26	99	0.04	82	0.62	-18
	500	0.03	-145	6.48	79	0.09	78	0.56	-23	
	1000	0.11	126	3.55	56	0.17	67	0.49	-40	
	1500	0.24	105	2.56	36	0.25	53	0.39	-62	
	2000	0.43	87	2.17	17	0.32	40	0.25	-95	

MOTOROLA SC {XSTRS/R F}

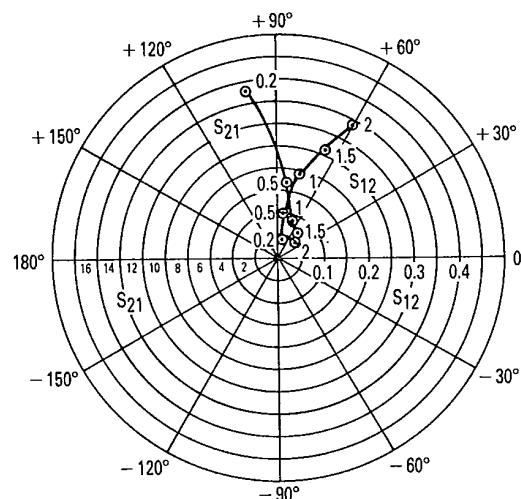
71 DE 6367254 0073008 3

SOT-89 MXR911



INPUT/OUTPUT REFLECTION COEFFICIENTS

versus FREQUENCY

 $V_{CE} = 10 \text{ V}, I_C = 30 \text{ mA}$ 

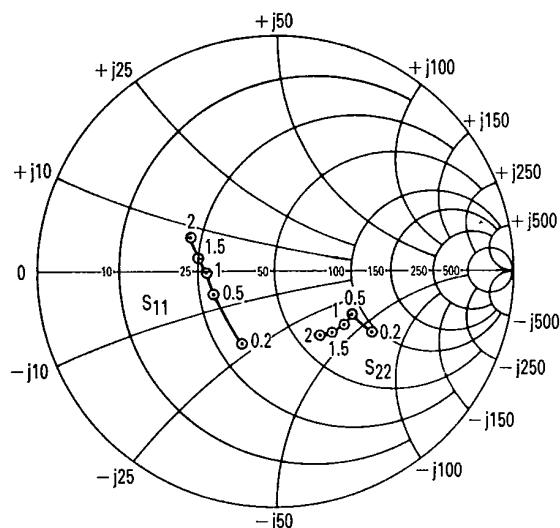
FORWARD AND REVERSE TRANSMISSION COEFFICIENTS versus FREQUENCY

 $V_{CE} = 10 \text{ V}, I_C = 30 \text{ mA}$

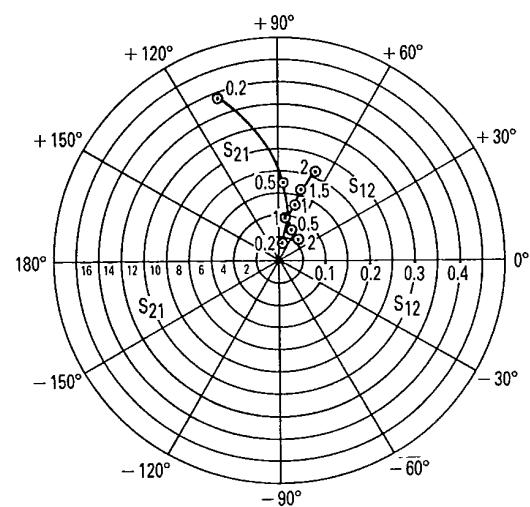
COMMON Emitter S-PARAMETERS

V_{CE} (Volts)	I_C (mA)	f (MHz)	S_{11}		S_{21}		S_{12}		S_{22}	
			$ S_{11} $	$\angle\phi$	$ S_{21} $	$\angle\phi$	$ S_{12} $	$\angle\phi$	$ S_{22} $	$\angle\phi$
10	2	200	0.80	-46	5.04	130	0.07	67	0.91	-18
		500	0.52	-100	3.58	100	0.11	56	0.74	-27
		1000	0.36	-173	2.32	72	0.16	59	0.64	-37
		1500	0.41	147	1.71	51	0.21	63	0.59	-50
		2000	0.48	118	1.36	37	0.27	65	0.56	-64
	5	200	0.65	-60	8.65	128	0.06	67	0.81	-24
		500	0.34	-115	5.10	93	0.10	65	0.61	-30
		1000	0.26	177	2.90	71	0.17	67	0.54	-38
		1500	0.32	143	2.11	53	0.23	64	0.49	-50
		2000	0.40	116	1.67	39	0.30	62	0.45	-65
	10	200	0.44	-72	11.87	118	0.05	70	0.70	-27
		500	0.21	-123	6.04	89	0.10	71	0.53	-31
		1000	0.19	171	3.27	70	0.18	70	0.47	-39
		1500	0.27	140	2.35	53	0.25	65	0.42	-53
		2000	0.35	115	1.88	41	0.32	60	0.38	-68
	20	200	0.27	-83	14.16	108	0.05	74	0.59	-28
		500	0.13	-138	6.57	85	0.10	75	0.47	-29
		1000	0.16	161	3.48	69	0.19	72	0.42	-39
		1500	0.24	135	2.49	53	0.26	65	0.37	-54
		2000	0.33	113	1.98	41	0.34	59	0.33	-71
	30	200	0.18	-95	14.93	103	0.04	77	0.54	-26
		500	0.11	-153	6.70	83	0.10	76	0.44	-27
		1000	0.16	156	3.52	68	0.19	73	0.41	-38
		1500	0.24	133	2.50	54	0.26	66	0.36	-54
		2000	0.33	112	2.00	42	0.34	60	0.32	-71
	50	200	0.15	-111	14.26	101	0.04	79	0.53	-22
		500	0.12	-160	6.45	82	0.09	77	0.46	-24
		1000	0.19	152	3.39	68	0.18	73	0.43	-37
		1500	0.27	130	2.41	53	0.26	67	0.38	-51
		2000	0.35	110	1.92	41	0.33	61	0.34	-68

SOT-23 MMBR911



INPUT/OUTPUT REFLECTION COEFFICIENTS
versus FREQUENCY
 $V_{CE} = 10$ V, $I_C = 30$ mA

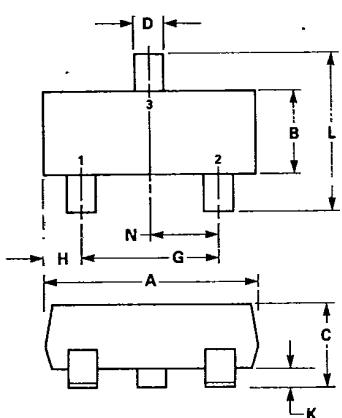


FORWARD AND REVERSE TRANSMISSION
COEFFICIENTS versus FREQUENCY
 $V_{CE} = 10$ V, $I_C = 30$ mA

COMMON Emitter S-PARAMETERS

V_{CE} (Volts)	I_C (mA)	f (MHz)	S_{11}		S_{21}		S_{12}		S_{22}	
			$ S_{11} $	$\angle \phi$	$ S_{21} $	$\angle \phi$	$ S_{12} $	$\angle \phi$	$ S_{22} $	$\angle \phi$
10	2	200	0.82	-45	4.14	145	0.06	66	0.88	-16
		500	0.60	-96	3.23	112	0.09	49	0.71	-27
		1000	0.47	-149	2.16	85	0.11	49	0.62	-34
		1500	0.46	-179	1.59	71	0.13	55	0.58	-43
		2000	0.47	162	1.35	57	0.16	62	0.56	-51
	5	200	0.66	-63	8.63	134	0.05	64	0.75	-25
		500	0.43	-117	5.29	100	0.07	58	0.55	-31
		1000	0.37	-163	3.05	82	0.11	63	0.48	-36
		1500	0.38	176	2.17	70	0.15	65	0.45	-44
		2000	0.40	160	1.81	57	0.19	65	0.43	-51
	10	200	0.49	-83	12.70	124	0.04	65	0.62	-30
		500	0.33	-134	6.42	94	0.07	66	0.44	-32
		1000	0.32	-171	3.53	80	0.12	70	0.41	-36
		1500	0.35	173	2.46	69	0.16	69	0.38	-45
		2000	0.37	159	2.04	58	0.20	66	0.35	-52
	20	200	0.36	-103	15.25	114	0.03	69	0.52	-32
		500	0.28	-149	6.95	90	0.06	72	0.39	-30
		1000	0.29	-176	3.73	78	0.12	73	0.37	-35
		1500	0.33	172	2.60	68	0.17	71	0.34	-43
		2000	0.36	158	2.14	58	0.21	67	0.32	-52
	30	200	0.32	-114	15.64	109	0.03	71	0.48	-29
		500	0.27	-156	6.92	88	0.06	73	0.38	-27
		1000	0.29	-178	3.71	78	0.12	74	0.37	-33
		1500	0.34	170	2.58	68	0.16	72	0.34	-44
		2000	0.37	156	2.13	57	0.21	68	0.32	-51

OUTLINE DIMENSIONS

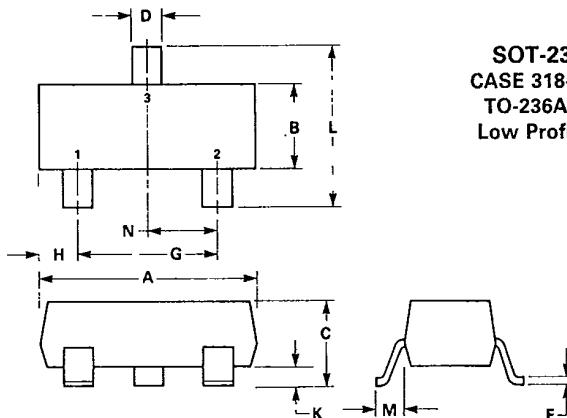


**SOT-23
CASE 318-02
TO-236AA
Standard**

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.80	3.04	0.1102	0.1197
B	1.20	1.40	0.0472	0.0551
C	0.85	1.20	0.033	0.0472
D	0.37	0.46	0.0150	0.0177
F	0.085	0.130	0.0034	0.0051
G	1.78	2.04	0.0701	0.0807
H	0.51	0.60	0.0200	0.0236
K	0.10	0.25	0.0040	0.0098
L	2.10	2.50	0.0830	0.0984
M	0.45	0.60	0.0180	0.0236
N	0.89	1.02	0.0350	0.0401

STYLE 6:
PIN 1. BASE
2. Emitter
3. Collector

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI
2. Y14.5M, 1982
CONTROLLING DIMENSION MILLIMETERS



**SOT-23
CASE 318-03
TO-236AB
Low Profile**

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.80	3.04	0.1102	0.1197
B	1.20	1.40	0.0472	0.0551
C	0.89	1.11	0.035	0.044
D	0.37	0.46	0.015	0.0177
F	0.085	0.130	0.0034	0.0051
G	1.78	2.04	0.0701	0.0807
H	0.51	0.60	0.0200	0.0236
K	0.013	0.100	0.0005	0.0040
L	2.10	2.50	0.0830	0.0984
M	0.45	0.60	0.0180	0.0236
N	0.89	1.02	0.0350	0.0401

STYLE 6:
PIN 1. BASE
2. Emitter
3. Collector

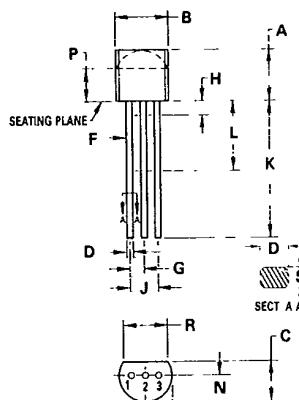
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI
2. Y14.5M, 1982.
CONTROLLING DIMENSION MILLIMETERS.

NOTES:
1. CONTOUR OF PACKAGE BEYOND ZONE "P" IS UNCONTROLLED.
2. DIM "F" APPLIES BETWEEN "H" AND "L". DIM "D" & "S" APPLIES BETWEEN "L" & 12.70 mm (0.5") FROM SEATING PLANE. LEAD DIM IS UNCONTROLLED IN "H" & BEYOND 12.70 mm (0.5") FROM SEATING PLANE.

STYLE 2:
PIN 1. BASE
2. Emitter
3. Collector

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.32	5.33	0.170	0.210
B	4.44	5.21	0.175	0.205
C	3.18	4.19	0.125	0.165
D	0.41	0.56	0.016	0.022
F	0.41	0.48	0.016	0.019
G	1.14	1.40	0.045	0.055
H	—	2.54	—	0.100
J	2.41	2.67	0.095	0.105
K	12.70	—	0.500	—
L	6.35	—	0.250	—
N	2.03	2.67	0.080	0.105
P	2.92	—	0.115	—
R	3.43	—	0.135	—
S	0.36	0.41	0.014	0.016

**TO-92
CASE 29-02
TO-226AA
PLASTIC**



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.40	4.60	0.174	0.181
B	2.29	2.60	0.091	0.102
C	1.40	1.60	0.056	0.062
D	0.36	0.48	0.015	0.018
E	1.62	1.80	0.064	0.070
F	0.44	0.53	0.018	0.020
G	1.50 BSC	—	0.059 BSC	—
J	0.35	0.44	0.014	0.017
K	0.80	1.04	0.032	0.040
L	3.00 BSC	—	0.118 BSC	—
N	2.04	2.28	0.081	0.089
P	3.94	4.25	0.156	0.167

STYLE 1:
PIN 1. BASE
2. COLLECTOR
3. Emitter

NOTES:
1. DIMENSIONS A AND B ARE DATUMS.
2. T IS SEATING PLANE.
3. POSITIONAL TOLERANCE FOR LEADS:
 $\phi 0.10 (0.004) @ T | B | G | A | S |$
4. DIMENSIONING AND TOLERANCING PER ANSI
Y14.5, 1973
5. CONTROLLING DIM: MILLIMETERS.